## **IN THE CLAIMS**

1 (Currently Amended). A method comprising:

blending a photodefinable polybenzoxazole precursor with a filler zirconia particles having a particle size of less than 100 nanometers.

Claims 2 and 3 (Canceled).

- 4 (Currently Amended). The method of claim 1 including blending the photodefinable precursor with a filler zirconia particles having a particle size less than 20 nanometers.
- 5 (Currently Amended). The method of claim 1 including blending the photodefinable precursor with a filler zirconia particles having a particle size of about 13 nanometers.
- 6 (Currently Amended). The method of claim 1 including curing the precursor after blending with a filler zirconia particles.
- 7 (Currently Amended). The method of claim 1 including blending the precursor with a filler so that the filler constitutes zirconia particles constitute from about 9 to about 20 percent by weight.
- 8 (Currently Amended). The method of claim 1 including forming a polymer from said blended precursor and filler zirconia particles.
- 9 (Currently Amended). A photodefinable polymer for semiconductor applications comprising:
- a photodefinable polybenzoxazole precursor; and

  a filler material zirconia particles having a particle size of less than 100 nanometers.

Claims 10 and 11 (Canceled).

12 (Currently Amended). The polymer of claim 9 wherein said filler material has zirconia particles have a particle size of less than 20 nanometers.

13 (Currently Amended). The polymer of claim 9 wherein said filler material has zirconia particles have a particle size of about 13 nanometers.

14 (Currently Amended). The polymer of claim 9 wherein said filler material emprises zirconia particles comprise from about 9 to about 20 percent by weight.

15 (Currently Amended). A photodefinable polymer for semiconductor applications comprising:

a photodefinable polybenzoxazole precursor; and

a-filler <u>zirconia particles</u> comprising about 9 to about 20 percent of the system, said filler <u>particles</u> having a particle size of less than 20 nanometers.

Claims 16 and 17 (Canceled).

18 (Currently Amended). The polymer of claim 15 wherein said filler has zirconia particles have a particle size of approximately 13 nanometers.

19 (Currently Amended). A polymer precursor for semiconductor applications comprising:

a photodefinable polybenzoxazole precursor; and a filler material zirconia particles having a particle size of less than 100

nanometers.

Claims 20 and 21 (Canceled).

- 22 (Currently Amended). The precursor of claim 19 wherein said filler material has zirconia particles have a particle size of less than 20 nanometers.
- 23 (Currently Amended). The precursor of claim 19 wherein said filler material has zirconia particles have a particle size of about 13 nanometers.
- 24 (Currently Amended). The precursor of claim 19 wherein said filler material emprises zirconia particles comprise about 9 to about 20 percent by weight.
  - 25 (Currently Amended). An integrated circuit comprising: a substrate; and
- a photodefinable polymer formed on said substrate, said polymer including a photodefinable resin and a filler material zirconia particles having a particle size of less than 100 nanometers.

Claims 26 and 27 (Canceled).

- 28 (Currently Amended). The circuit of claim 25 wherein said filler material has zirconia particles have a particle size of less than 20 nanometers.
- 29 (Currently Amended). The circuit of claim 25 wherein said filler material has zirconia particles have a particle size of about 13 nanometers.
- 30 (Currently Amended). The circuit of claim 25 wherein said filler material emprises zirconia particles comprise from about 9 to about 20 percent by weight.